

April 25, 2012

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Fast Sampler/Pulser IC Technology Enables New Applications

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Pulser(bottom) acts like a switch that is 2



Some types of microwave pulsers and samplers:

- Pulser: Step recovery diode
- Sampler: Step recovery diode driving Schottky Diode bridge
- Pulser: Nonlinear Transmission Line(NLTL)
- Sampler: " driving Schóttky
- Pulser: Avalanche Transistor
- Pulser or Sampler: Pulsed picosecond laser striking Photoconductive semiconductor
- Current steering pulsers and samplers
- Overview: M. Kahrs, 50 Years of RF and Microwave Sampling. IEEE Transactions on Microwave Theory and Techniques, VOL. 51, NO. 6, JUNE 2003



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Rapid Automatic Cascode Exchange (RACE) Sampler/Pulser





Pulse trains generated by monolithic RACE pulser

- Time Domain Waveform for 2GPPS pulse train.
 - Pulse width approx. 10ps on chip
 - Displayed pulse width 14ps, due to connector losses, convolution with scope response

- Frequency spectrum for 1GPPS pulse train
 - Comb tooth every 1GHz
 - Declining output as frequency increases due to finite pulse width, connector and cable losses





Basic Electrical Sampler/Pulser Applications

- Sampler followed by low-pass filter = downconverter
- Pulser (sampler feeding load directly) = comb generator
- Modulated pulser driving an antenna = narrowband upconvertor
 RF center frequencies are multiples of pulser repetition rate
- Sampler sampling a pulser running at an offset frequency is a comb spectrometer.
 - Reflection vs. Transmission spectrometer depending on location of sampler
 - If sampler and pulser are on same side/port of DUT, then acts like TDR
 - If pulser is on one port of DUT and sampler is on other port, acts like TDT



Quick Background – IF (bandpass) Sampling and Frequency Comb Generation

- Samplers/pulsers with high analog BW and moderate sampling rate can capture or generate very high frequencies
 - Requires Analog BW >> Sampling rate
 - BP Filtering for desired band of interest (centered around nth comb tooth)
- Sampler Analog bandwidth
 - Highest Frequency governed by the width of the sampling aperture.
 - Typical sample/pulse widths with "R.A.C.E." technology
 - 7ps 30GSPS in production InP ICs
 - 10ps 20GSPS in production SiGe ICs
 - 60ps FWHM 2GPPS 20V differential pulser ICs simulated in GaN
- Sampling (repetition) rate
 - Higher sampling rate results in stronger (but sparser) frequency harmonics.
 - Does not affect analog bandwidth





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100GHz Sampling and Pulse Generation on Single Monolithic IC

• TDR/TDT/VNA Front-End IC



TDR/VNA front end using integrated sampler pulser IC

Fast Monolithic Sampler/Pulser: 100 GHz BW, 110dB DR



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"No-Load" TDR/Sampler IC for in-line PCIe, 10GE PHY measurement Enables Minimally Invasive Real-Time Link Analysis

- IC provides Hi-Z TDR / Eyepattern measurement of PCIe or 10GE lanes.
- Coherent TDR has little affect on the bit error rate of the active link. Eye pattern view at same time.
- IC provides downsampled output and raw output.
- Allows for continuous link characterization using low bandwidth oscilloscope or ADC.
- Eliminates 50 ohm loading due to transmission lines to remotely located TDR

Integrated in-line PCIe or 10Gb Ethernet TDR / Sampler







IC shown monitors high-speed serial link when mounted on simple pass through extender. TDR plots shown were generated using Furaxa InP sampler/pulser IC. Reflected pulse widths are approximately 15 ps.



Monolithic Sampler/Pulser enables Microwave Transceiver

- High rep rate monolithic matched arrays of samplers/pulsers replace mixers and power-hungry microwave LO & divide chain.
 - Previous microwave samplers lacked sufficient repetition rate to allow them to replace mixers in most communications applications.
 - RX: Instead use samplers and medium frequency oscillators
 - TX: Instead use pulsers and medium frequency oscillators
- Multiple matched samplers/pulsers on one IC allow power to be concentrated in few comb teeth
 - Easier filtering due to wide spacing between harmonics
 - Arrayable, high rep rate samplers/pulsers approach mixer performance, but at much lower total system cost, size and power
 - Allows Independent generation/detection of odd and even harmonics
- Inherent Up/Downconversion and Modulation Capability
 - Pulse amplitude and width can be dynamically controlled



Conventional 60 GHz WPAN Tx architecture, capable of simple AM or OOK modulation, uses microwave VCO, frequency divide chain, frequency doubler, 60 GHz mixer, Power Amplifier (PA), and BALUN. Heavy power usage in VCO, Frequency divide chain, mixer.



Simplified 60 GHz Tx using dual-edge pulser for frequency doubling and subsequent filter-based selection of 2nd comb tooth to create 60GHz output.

Advantage: lower size, power. Disadvantage: need to Suppress



Block Diagram of dual-band monolithic samplerbased receiver IC, currently undergoing testing. "Dual-Edge" samplers may be set to be selective to even vs odd harmonics of LO







Wide comb spacing simplifies filtering, increases power, SNR



Odd Comb Frequencies:

Multiplier	Frequency Range
3	27-42 GHz
7	63-98 GHz







Low Power 18-75GHz downconversion IC, Fabricated in InP



Microwave Receiver Board

 Single Chip plus low-cost components make up 18-75GHz receiver



I and Q IF signals when downconverting ~54GHz CW signal. C can implement AGC by reducing gain by lowering sampler V3

- voltage this delays the start of the aperture, making it narrower: IQPhaseShift42.5GHzDncnvrt_AGC2trim.mp4
- IQPhaseShift42.5GHzDncnvrt AGC2trim¹⁰MOV

FURAXA -21.65 dBm 1.60000000 GHz -10 CEM #Att Ø de SWT 100 ms Ref -1.0 ---20--1 AP CLRHR

rejection of alternate comb teeth (odd vs even) and rightmost (2GHz) spur due to reference oscillator harmonic feedthrough 20



IF signal with 4.8 GHz CF, when sampler is downconverting 43.2GHz signal, using sector of the sector

- Detector) is fed to on-chip downconversion samplers configured for
- even-comb-only receptivity. Sampler thereby effectively samples
- at 48GHz resulting in 4.8GHz IF when fed with



- Operation of Sampling Phase Reference clockpip (GHz SAW-stabilized oscillator (Sampler Samples VCO every 1ns). SPD output (error signal) is fed to integrator that then adjusts VCO frequency 22





Sampling Phase Detector output when not locked

- Left photo is ~50MHz beat when 24.05MHz VCO is sampled by SPD at 500MSPS sample rate.
- Right photo is ~50MHz beat when 36.05MHz VCO is sampled by SPD at 500MSPS sample rate.
- •



Sampling Phase Detector in unlocked (left) and locked(right) states. IF output is shown at bottom (left horizontal scale is 10MHz/div)





Microwave Sampler-based Downconverter Driving PCIe bus dual channel 500MSPS 14-bit ADC board. IF signal processing 25



PC Sampler/Pulser Receiver Control

- Panel using LabView
 User can select VCO range, VCO Frequency, Sampler VG3, Pulser
 Amplitude Allows Receiver settings to be saved, and facilitates
- low-cost host PC-based IF signal processing. •



Direct Arbitrary UWB Waveform Synthesis with







POSSIBLE FUTURE APPLICATIONS

- Up/down-conversion without microwave oscillators
- Pre-emphasis for high speed communication links
- LPOI/LPOD UWB transceivers with spectral shaping
- Ultra-low power UWB RFID tags
- Direct chip-to-chip communication using UWB pulses, replacing PCB traces
- Vehicular and military RADAR
- Low cost spectrum and vector network analyzers
- Time gated microwave medical imaging systems (eg. Helmet-sized Battlefield cranial imager)
- Non-invasive blood chemistry spectroscopy?
- Driver for TeraHertz diodes for explosives detection
 and other spectroscopy

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Though shown in initial modular form, much higher levels of integration could be achieved, ultimately a single IC



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- 2. J.M. Libove and S.J. Chacko, "*Methods, Apparatuses and Systems for Sampling or Pulse Generation*", US Patent 6,433,720, August 13, 2002.
- 3. J.M. Libove, B.R. Illingworth, S.J.Chacko, H.L. Levitt, "Monolithic Sampler/Pulser Exceeds 100 GHz", Microwave Journal, August 2008, pp 86-105.
- 4. Levitt, H.L., Libove, J.M., Illingworth, B.R., Seay, N.S., Jain, N., "Direct Sampling Millimeter Wave RFIC Tuner Development", Government Microcircuit and Critical Technology Conference 2010 (GOMACtech2010), Reno, NV, 22-25. March 2010.
- 5. H. Levitt, J. Libove, N Seay, M Chu, M Leroy, J. McDonald, *Integrated Millimeter Wave Tuners Utilizing Indium Phosphide and Silicon Germanium Technology*, MilComm11, Nov.8, 2011, Baltimore, MD.